Dynamic Engineers Inc.

2550 Gray Falls Dr., Suite#128, Houston, TX, 77077 USA TEL: 1-281-870-8822 EMAIL:Sales@DynamicEnq.com

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Ultra Low Power Miniature Low Profile OCXO

Features and Benefits

14DIP Compatible 8mm Height Packaging Very Low Power Consumption: 0.15W at +25°C

Fast Warming-up: 60 s typical

Low Aging: +/-2.0 ppb/day, +/-200 ppb/year Wide Frequency range: 8 – 120 MHz

Typical Applications

Portable Wireless Communications Mobile Test equipment Synthesizers Battery Powered Application

Description

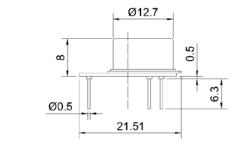
The OCXO3307LP-20MHz-A-V utilizes the internal heating resonator (IHR) technology incorporating the whole oven system together with the crystal plate inside the TO-8 vacuum holder. Such an OCXO concept results in radical reduction of its volume, power consumption and warm-up time. In spite of the miniature sizes and extremely low power consumption such oscillators exhibit excellent temperature stability, low phase-noise and aging rate being at the level of high-end OCXOs using conventional oven designs.

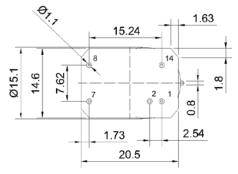
Mechanical Drawing & Pin Connections

Drawing No:

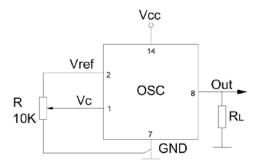
MD140075-1

Physical dimensions





Schematic connections



Pin	Signal
1	Electrical tuning
2	Reference voltage
7	GND
8	RF Out
14	+V Supply

Unit: mm



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Specifications

Oscillator Specification		Sym	Condition	Value				N. d		
				Min.	Тур.	Max.	Unit	Note		
Operational Frequency		F _{nom}			20.000000		MHz			
Initial tolerance			at +25°C, Vc=Vc0	-0.2		+0.2	ppm			
RF Output		•					,	,		
Waveform : LVCMOS					HCMOS					
Load			5 pF in parallel with 10K		5//10K		pF//K			
H-level voltage							·			
			Vcc=3.3V	2.4			V			
L-level voltage						0.4	V			
Duty cycle				45		55	%			
Rise/Fall time						10	ns			
Sub-harmonics level					none					
Frequency cont	rol									
Control voltage range		V _c		0		2.8	V			
Frequency Turning Range				+/-0.5	+/-1	-	ppm	+		
Reference Voltage		V_{ref}			2.8		V			
Power Supply										
Voltage		V _{cc}			3.3		V			
			Warm-up state		0.7					
Power consumpt	Power consumption		-		_		W			
			@ +25°C steady state		0.15					
Warm-up Time:		T_{up}	to Δf/f = 1e ⁻⁷ at +25°C		60		s	ref. to frequencyafter 15 min		
Frequency Stab	oility									
Vs.Temperature			Ref. 25°C			+/- 50	ppb			
Vs. Supply Voltage			Ref Vcc typ.		+/-2		ppb			
vs. direction			worst direction			+/-1	ppb/g			
Aging	per day		after 30days of operation			+/-2	ppb			
Aging	first year		, ,			+/-200	ppb			
			1 Hz		-87					
SSB Phase noise			10 Hz		-117		dBc/Hz			
			100 Hz		-140					
			1 KHz		-150					
			10KHz		-160					
			100 KHz		-163					
Environmental (
Storage temperature range		-60°C to 90°C								
Operating temperature range		-40°C to 85°C								
Humidity		Non-condensing 95%								
Mechanical Shock		MIL-STD-202, 30G half sine pulse, 11 ms								
Vibration		MIL-STD-202, 5G swept sine, 10 to 2000 Hz								
Washing Condition		Washing v	Washing with water or alcohol based detergent allowed only with final enough drying stage							
Soldering Condit	Soldering Conditions Hand solder only – not reflow compatible 260°C 10s(on pins)									